

QLD103E-xx50-ST

1030 / 1064 nm >50mW DFB Laser TO-CAN

C00253-01 May 2021



1. **DESCRIPTION**

The QLD103E-xx50 is a 1030 / 1064-nm distributed feedback (DFB) laser suitable for various applications, such as seeder, measurement, sensing, frequency doubling and etc. The laser is mounted into a TO-56 header including a monitor PD for optical power control and hermetic sealed with a flat type cap.

2. FEATURES

- Single longitudinal mode operation at 1030 nm and 1064 nm
- CW and short pulsed operation
- Φ 5.6mm TO-CAN package
- Monitor PD included

3. APPLICATIONS

- Seeder
- Measurement
- Sensing
- Frequency doubling
- Short pulse generation

4. ABSOLUTE MAXIMUM RATINGS

		$(T_c = 25^{\circ}C, unless other)$	$(T_c = 25^{\circ}C, unless otherwise specified)$		
PARAMETER	SYMBOL	RATING	UNIT		
Optical Output power	Po	60	mW		
LD Forward Current	$I_{\rm F}$	180	mA		
LD Reverse Voltage	V _{RLD}	2	V		
PD Forward Current	I _{FPD}	2	mA		
PD Reverse Voltage	V _{RPD}	10	V		
Operation Temperature	T _c	15 to 45	°C		
Storage Temperature	T _{stg}	-40 to 85	°C		
Lead Soldering Temperature (10 s)	T _{sld}	260	°C		

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5. OPTICAL AND ELECTRICAL CHARACTERISTICS

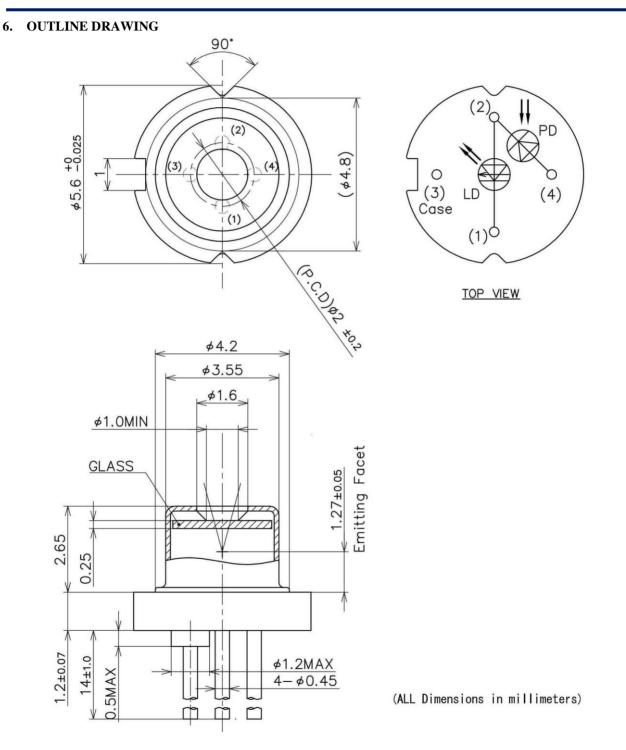
				$(T_{LD} = 25^{\circ}C, \text{ unless otherwise specified})$				
PARAMETER		SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT	
Peak	QLD103E-6450	2	CW, $P_0 = 50 \text{ mW}$	1059*	1064	1069*	nm	
Wavelength	QLD103E-3050	λ_p		1025*	1030	1035*	nm	
Temperature C	coefficient of λ_p	$d\lambda_p/dT$	CW	-	0.08	-	nm/K	
Current Coefficient of λ_p		$d\lambda_p/dI$	CW	-	0.008	-	nm/mA	
Optical Output Power		Po	CW	50	-	-	mW	
Threshold Current		I _{th}	CW	-	20	-	mA	
Operation Current		I _{op}	CW, $P_0 = 50 \text{ mW}$	-	100	150	mA	
Operation Voltage		V _{op}	CW, $P_0 = 50 \text{ mW}$	-	1.5	2.0	V	
Sidemode Sup	pression Ratio	SMSR	CW, $P_0 = 50 \text{ mW}$	-	40	-	dB	
Far filed patter	n horizontal	θ_h	CW, $P_0 = 50 \text{ mW}$	-	10	-	deg.	
Far filed pattern vertical		$\theta_{\rm v}$	CW, $P_0 = 50 \text{ mW}$	-	22	-	deg.	
Monitor PD Cu	urrent	Im	CW, P ₀ =50 mW, V _{RPD} =5 V	-	250	-	μΑ	
Dark current (I	PD)	Id	V _{RPD} =5 V	-	-	20	nA	

*Peak wavelength torelance of +/- 1nm is available as an option.

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7. NOTICE

• Safety Information

This product is classified as Class 3B laser product, and complies with 21 CFR Part 1040.10. Please do not take a look laser lighting in operations since laser devices may cause troubles to human eyes. Please do not eat, burn, break and make chemical process of the products since they contain GaAs material.

• Handling products

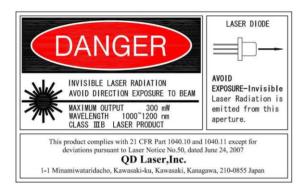
Semiconductor lasers are easily damaged by external stress such as excess temperature and ESD.

Please pay attention to handling products, and use within range of maximum ratings.

QD Laser takes no responsibility for any failure or unusual operation resulting from improper handling, or unusual physical or electrical stress.

• RoHS

This product conforms to RoHS compliance related Directive (EU) 2015/863.





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